



Functional Block Diagram

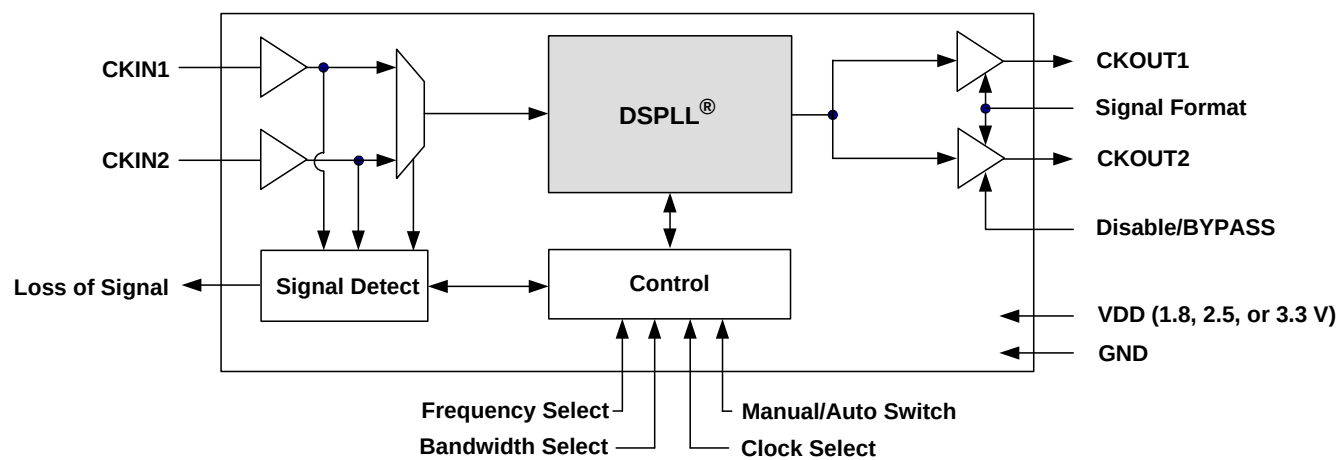


TABLE OF CONTENTS

<u>Section</u>	<u>Page</u>
1. Electrical Specifications	4
1.1. Three-Level (3L) Input Pins (No External Resistors)	9
1.2. Three-Level Input Pins (Example with External Resistors)	9
2. Functional Description	13
2.1. Further Documentation	13
3. Pin Descriptions: Si5322	14
4. Ordering Guide	18
5. Package Outline: 36-Pin QFN	19
6. Land Pattern: 36-Pin QFN	20
7. Top Marking	22
7.1. Si5322 Top Marking (QFN)	22
7.2. Top Marking Explanation	22
Document Change List	23
Contact Information	24

1. Electrical Specifications

Table 1. Recommended Operating Conditions
 $(V_{DD} = 1.8 \pm 5\%, 2.5 \pm 10\%, \text{ or } 3.3 \text{ V} \pm 10\%, T_A = -40 \text{ to } 85^\circ\text{C})$

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Temperature Range	T_A		-40	25	85	$^\circ\text{C}$
Supply Voltage	V_{DD}	3.3 V nominal	2.97	3.3	3.63	V
		2.5 V nominal	2.25	2.5	2.75	V
		1.8 V nominal	1.71	1.8	1.89	V

Note: All minimum and maximum specifications are guaranteed and apply across the recommended operating conditions. Typical values apply at nominal supply voltages and an operating temperature of 25°C unless otherwise noted.

Table 2. DC Characteristics
 $(V_{DD} = 1.8 \pm 5\%, 2.5 \pm 10\%, \text{ or } 3.3 \text{ V} \pm 10\%, T_A = -40 \text{ to } 85^\circ\text{C})$

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Supply Current (Supply current is independent of V _{DD})	I _{DD}	LVPECL Format 622.08 MHz Out All CKOUTs Enabled ¹	—	251	279	mA
		LVPECL Format 622.08 MHz Out Only 1 CKOUT Enabled ¹	—	217	243	mA
		CMOS Format 19.44 MHz Out All CKOUTs Enabled	—	204	234	mA
		CMOS Format 19.44 MHz Out Only CKOUT1 Enabled	—	194	220	mA
CKIN Input Pins						
Input Common Mode Voltage (Input Threshold Voltage)	V _{ICM}	1.8 V ±5%	0.9	—	1.4	V
		2.5 V ±10%	1.0	—	1.7	V
		3.3 V ±10%	1.1	—	1.95	V
Input Resistance	CKN _{RIN}	Single-ended	20	40	60	kΩ
Input Voltage Level Limits	CKN _{VIN}	See Note ²	0	—	V _{DD}	V
Single-Ended Input Voltage Swing	V _{ISE}	f _{CKIN} ≤ 212.5 MHz See Figure 2.	0.2	—	—	V _{PP}
		f _{CKIN} > 212.5 MHz See Figure 2.	0.25	—	—	V _{PP}

Notes:

1. LVPECL outputs require nominal $V_{DD} \geq 2.5 \text{ V}$.
2. No overshoot or undershoot.
3. This is the amount of leakage that the 3L inputs can tolerate from an external driver. See Figure 3 on page 9. In most designs, an external resistor voltage divider is recommended.

Table 2. DC Characteristics (Continued)(V_{DD} = 1.8 ±5%, 2.5 ±10%, or 3.3 V ±10%, T_A = –40 to 85 °C)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Differential Input Voltage Swing	V _{ID}	f _{CKIN} ≤ 212.5 MHz See Figure 2.	0.2	—	—	V _{PP}
		f _{CKIN} > 212.5 MHz See Figure 2.	0.25	—	—	V _{PP}
Output Clocks (CKOUTn) ¹						
Common Mode	CKO _{VCM}	LVPECL 100 Ω load line-to-line	V _{DD} – 1.42	—	V _{DD} – 1.25	V
Differential Output Swing	CKO _{VD}	LVPECL 100 Ω load line-to-line	1.1	—	1.9	V _{PP}
Single-ended Output Swing	CKO _{VSE}	LVPECL 100 Ω load line-to-line	0.5	—	0.93	V _{PP}
Differential Output Voltage	CKO _{VD}	CML 100 Ω load line-to-line	350	425	500	mV _{PP}
Common Mode Output Voltage	CKO _{VCM}	CML 100 Ω load line-to-line	—	V _{DD} – 0.36	—	V
Differential Output Voltage	CKO _{VD}	LVDS 100 Ω load line-to-line	500	700	900	mV _{PP}
		Low swing LVDS 100 Ω load line-to-line	350	425	500	mV _{PP}
Common Mode Output Voltage	CKO _{VCM}	LVDS 100 Ω load line-to-line	1.125	1.2	1.275	V
Differential Output Resistance	CKO _{RD}	CML, LVDS, LVPECL	—	200	—	Ω
Output Voltage Low	CKO _{VOLLH}	CMOS	—	—	0.4	V
Output Voltage High	CKO _{VOHLH}	V _{DD} = 1.71 V CMOS	0.8 x V _{DD}	—	—	V
Output Drive Current	CKO _{IO}	CMOS Driving into CKO _{VOL} for out- put low or CKO _{VOH} for output high. CKOUT+ and CKOUT– shorted externally.				
		V _{DD} = 1.8 V	—	7.5	—	mA
		V _{DD} = 3.3 V	—	32	—	mA

Notes:

1. LVPECL outputs require nominal V_{DD} ≥ 2.5 V.
2. No overshoot or undershoot.
3. This is the amount of leakage that the 3L inputs can tolerate from an external driver. See Figure 3 on page 9. In most designs, an external resistor voltage divider is recommended.

Table 2. DC Characteristics (Continued)(V_{DD} = 1.8 ±5%, 2.5 ±10%, or 3.3 V ±10%, T_A = –40 to 85 °C)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
2-Level LVCMOS Input Pins						
Input Voltage Low	V _{IL}	V _{DD} = 1.71 V	—	—	0.5	V
		V _{DD} = 2.25 V	—	—	0.7	V
		V _{DD} = 2.97 V	—	—	0.8	V
Input Voltage High	V _{IH}	V _{DD} = 1.89 V	1.4	—	—	V
		V _{DD} = 2.25 V	1.8	—	—	V
		V _{DD} = 3.63 V	2.5	—	—	V
Input Low Current	I _{IL}		—	—	50	μA
Input High Current	I _{IH}		—	—	50	μA
Weak Internal Input Pull-up Resistor	R _{PUP}		—	75	—	kΩ
Weak Internal Input Pull-down Resistor	R _{PDN}		—	75	—	kΩ
3-Level Input Pins						
Input Voltage Low	V _{ILL}		—	—	0.15 × V _{DD}	V
Input Voltage Mid	V _{IMM}		0.45 × V _{DD}	—	0.55 × V _{DD}	V
Input Voltage High	V _{IHH}		0.85 × V _{DD}	—	—	V
Input Low Current	I _{ILL} ³		–20	—	—	μA
Input Mid Current	I _{IMM} ³		–2	—	2	μA
Input High Current	I _{IHH} ³		—	—	20	μA
Notes: 1. LVPECL outputs require nominal V_{DD} ≥ 2.5 V. 2. No overshoot or undershoot. 3. This is the amount of leakage that the 3L inputs can tolerate from an external driver. See Figure 3 on page 9. In most designs, an external resistor voltage divider is recommended.						

Table 2. DC Characteristics (Continued)(V_{DD} = 1.8 ±5%, 2.5 ±10%, or 3.3 V ±10%, T_A = -40 to 85 °C)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
LVC MOS Output Pins						
Output Voltage Low	V _{OL}	I _O = 2 mA V _{DD} = 1.71 V	—	—	0.4	V
		I _O = 2 mA V _{DD} = 2.97 V	—	—	0.4	V
Output Voltage High	V _{OH}	I _O = -2 mA V _{DD} = 1.71 V	V _{DD} - 0.4	—	—	V
		I _O = -2 mA V _{DD} = 2.97 V	V _{DD} - 0.4	—	—	V
Disabled Leakage Current	I _{OZ}	RST = 0	-100	—	100	μA

Notes:

1. LVPECL outputs require nominal V_{DD} ≥ 2.5 V.
2. No overshoot or undershoot.
3. This is the amount of leakage that the 3L inputs can tolerate from an external driver. See Figure 3 on page 9. In most designs, an external resistor voltage divider is recommended.

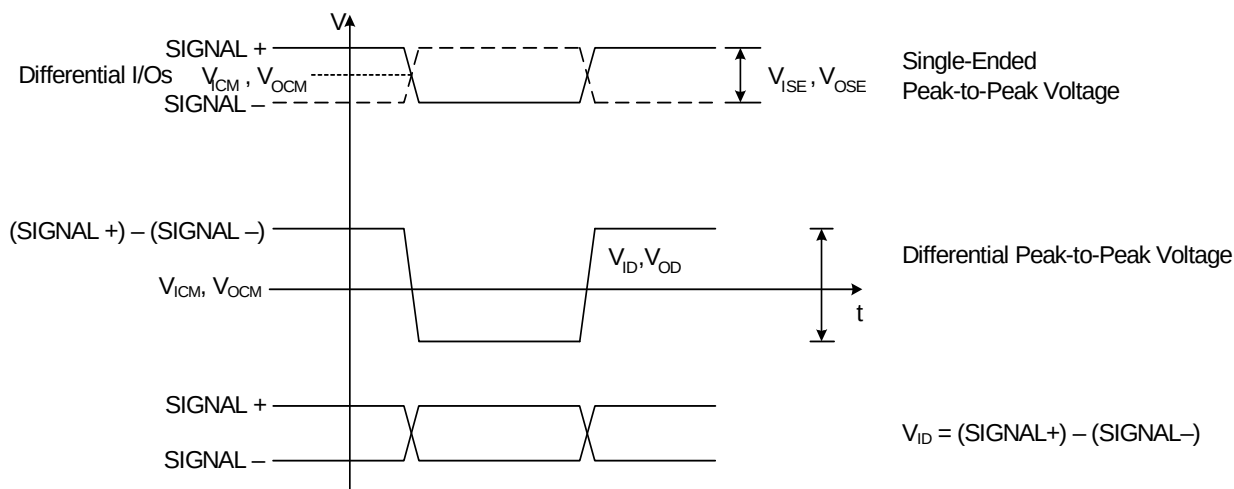
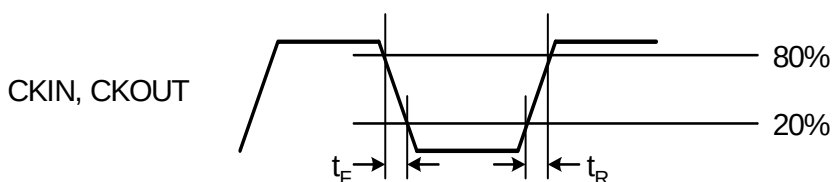
**Figure 1. Voltage Characteristics****Figure 2. Rise/Fall Time Characteristics**

Table 3. AC Characteristics(V_{DD} = 1.8 ±5%, 2.5 ±10%, or 3.3 V ±10%, T_A = –40 to 85 °C)

Parameter	Symbol	Test Condition	Min	Typ	Max	Units
CKIN Input Pins						
Input Frequency	CKN _F		19.44	—	707.35	MHz
Input Duty Cycle (Minimum Pulse Width)	CKN _{DC}	Whichever is smaller (i.e., the 40%/60% limitation applies only to high clock frequencies)	40	—	60	%
			2	—	—	ns
Input Capacitance	CKN _{CIN}		—	—	3	pF
Input Rise/Fall Time	CKN _{TRF}	20–80% See Figure 2	—	—	11	ns
CKOUTn Output Pins						
Output Frequency (Output not configured for CMOS or disable)	CKO _{OF}		19.44	—	1050	MHz
Maximum Output Frequency in CMOS Format	CKO _{FMC}		—	—	212.5	MHz
Single-ended Output Rise/Fall (20–80%)	CKO _{TRF}	CMOS Output V _{DD} = 1.71 C _{load} = 5 pF	—	—	8	ns
		CMOS Output V _{DD} = 2.97 C _{load} = 5 pF	—	—	2	ns
Differential Output Rise/Fall Time	CKO _{TRF}	20 to 80 %, f _{OUT} = 622.08	—	230	350	ps
Output Duty Cycle Differential Uncertainty	CKO _{DC}	100 Ω Load Line to Line Measured at 50% Point (not for CMOS)	—	—	±40	ps
LVC MOS Input Pins						
Minimum Reset Pulse Width	t _{RSTMIN}		1	—	—	μs
Input Capacitance	C _{IN}		—	—	3	pF
LVC MOS Output Pins						
Rise/Fall Times	t _{RF}	C _{LOAD} = 20 pf See Figure 2	—	25	—	ns
LOSn Trigger Window	LOS _{TRIG}	From last CKIN↑ to LOS↑		—	750	μs
PLL Performance						
Output Clock Phase Change	t _{P_STEP}	After clock switch f ₃ ≥ 128 kHz	—	200	—	ps
Closed Loop Jitter Peaking	J _{PK}		—	0.05	0.1	dB
Jitter Tolerance	J _{TOL}	BW determined by BWSEL[1:0]	5000/ BW	—	—	ns pk- pk
Spurious Noise	SP _{SPUR}	Max spur @ n x f ₃ (n ≥ 1, n x f ₃ < 100 MHz)	—	–93	–70	dBc
Phase Change due to Temperature Variation	t _{TEMP}	Max phase changes from – 40 to +85 °C	—	300	500	ps

1.1. Three-Level (3L) Input Pins (No External Resistors)

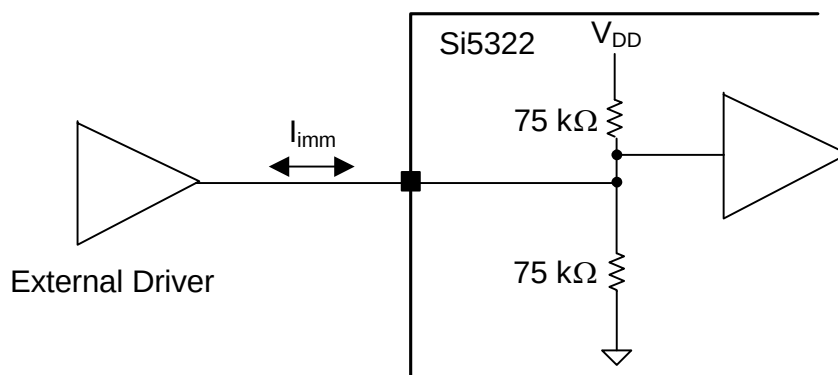
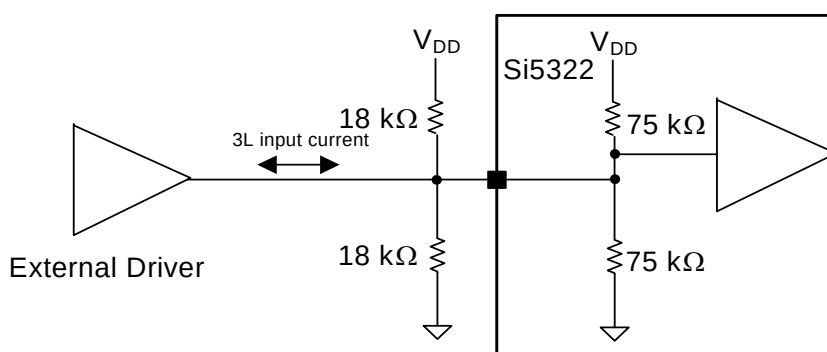


Figure 3. Three-Level Input Pins

1.2. Three-Level Input Pins (Example with External Resistors)



One of eight resistors from a Panasonic EXB-D10C183J (or similar) resistor pack

Figure 4. Three-Level Input Pins

Table 4. Three-Level Input Pins^{1,2,3,4}

Parameter	Min	Max
Input Low Current	$-30\text{ }\mu\text{A}$	—
Input Mid Current	$-11\text{ }\mu\text{A}$	$-11\text{ }\mu\text{A}$
Input High Current	—	$-30\text{ }\mu\text{A}$

Notes:

1. The current parameters are the amount of leakage that the 3L inputs can tolerate from an external driver using the external resistor values indicated in this example. In most designs, an external resistor voltage divider is recommended.
2. Resistor packs are only needed if the leakage current of the external driver exceeds the current specified in Table 2, I_{imm} . Any resistor pack may be used (e.g., Panasonic EXB-D10C183J). PCB layout is not critical.
3. If a pin is tied to ground or V_{DD} , no resistors are needed.
4. If a pin is left open (no connect), no resistors are needed.

Table 5. Performance Specifications^{1, 2, 3, 4}(V_{DD} = 1.8 ±5%, 2.5 ±10%, or 3.3 V ±10%, T_A = -40 to 85 °C)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Jitter Generation f _{IN} = f _{OUT} = 622.08 MHz, LVPECL Output Format BW = 877 Hz	J _{GEN}	50 kHz–80 MHz	—	.47	—	ps rms
		12 kHz–20 MHz	—	.48	—	ps rms
		4 MHz–80 MHz	—	.23	—	ps rms
Phase Noise f _{IN} = f _{OUT} = 622.08 MHz LVPECL Output Format	CKO _{PN}	1 kHz offset	—	–90	—	dBc/Hz
		10 kHz offset	—	–113	—	dBc/Hz
		100 kHz offset	—	–118	—	dBc/Hz
		1 MHz offset	—	–132	—	dBc/Hz

Notes:

1. BWSEL [1:0] loop bandwidth settings provided in by DSPLLsim.
2. V_{DD} = 3.3 V
3. T_A = 85 °C
4. Test condition: f_{IN} = 622.08 MHz, f_{OUT} = 622.08 MHz, LVPECL clock input: 1.19 V_{ppd} with 0.5 ns rise/fall time (20-80%), LVPECL clock output.

Table 6. Thermal Characteristics(V_{DD} = 1.8 ±5%, 2.5 ±10%, or 3.3 V ±10%, T_A = -40 to 85 °C)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Thermal Resistance Junction to Ambient	θ _{JA}	Still Air	—	32	—	°C/W
Thermal Resistance Junction to Case	θ _{JC}	Still Air	—	14	—	°C/W

Table 7. Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
DC Supply Voltage	V _{DD}	–0.5 to 3.8	V
LVC MOS Input Voltage	V _{DIG}	–0.3 to (V _{DD} + 0.3)	V
CKINn Voltage Level Limits	CKN _{VIN}	0 to V _{DD}	V
Operating Junction Temperature	T _{JCT}	–55 to 150	°C
Storage Temperature Range	T _{STG}	–55 to 150	°C
ESD HBM Tolerance (100 pF, 1.5 kΩ); All pins except CKIN+/CKIN–		2	kV
ESD MM Tolerance; All pins except CKIN+/CKIN–		150	V
ESD HBM Tolerance (100 pF, 1.5 kΩ); CKIN+/CKIN–		750	V
ESD MM Tolerance; CKIN+/CKIN–		100	V
Latch-Up Tolerance		JESD78 Compliant	

Note: Permanent device damage may occur if the Absolute Maximum Ratings are exceeded. Functional operation should be restricted to the conditions as specified in the operation sections of this data sheet. Exposure to absolute maximum rating conditions for extended periods of time may affect device reliability.

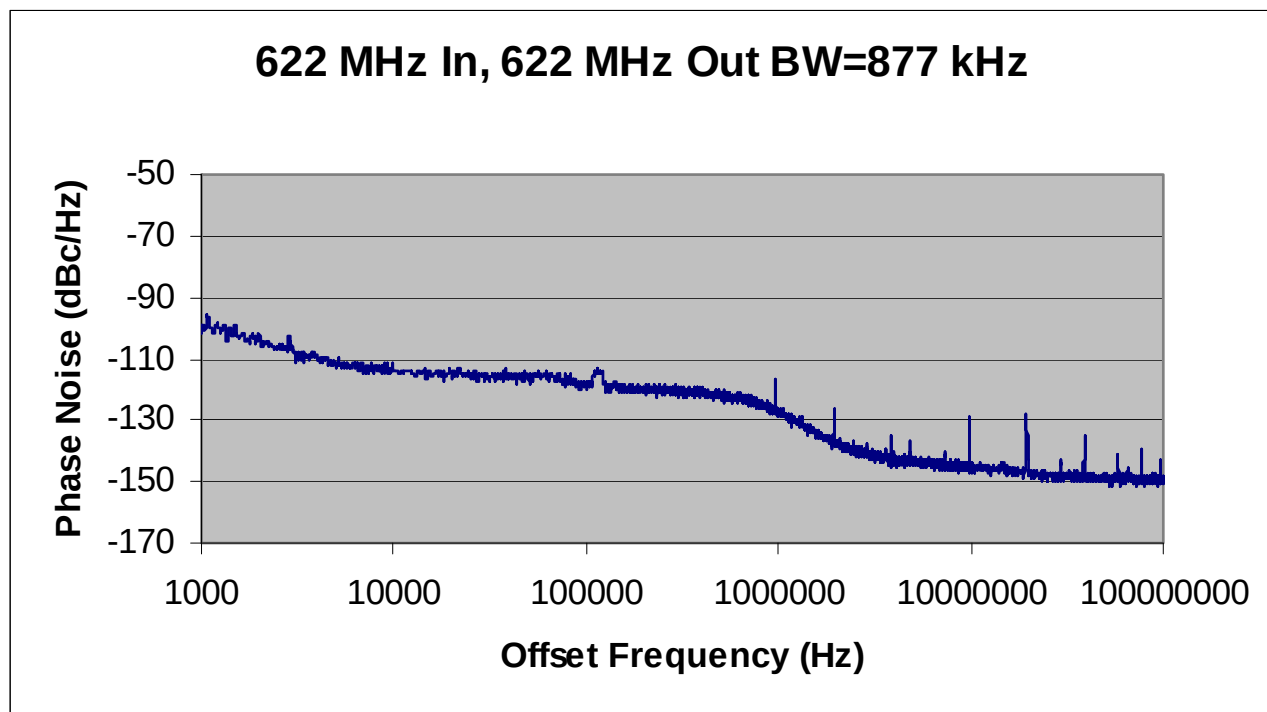
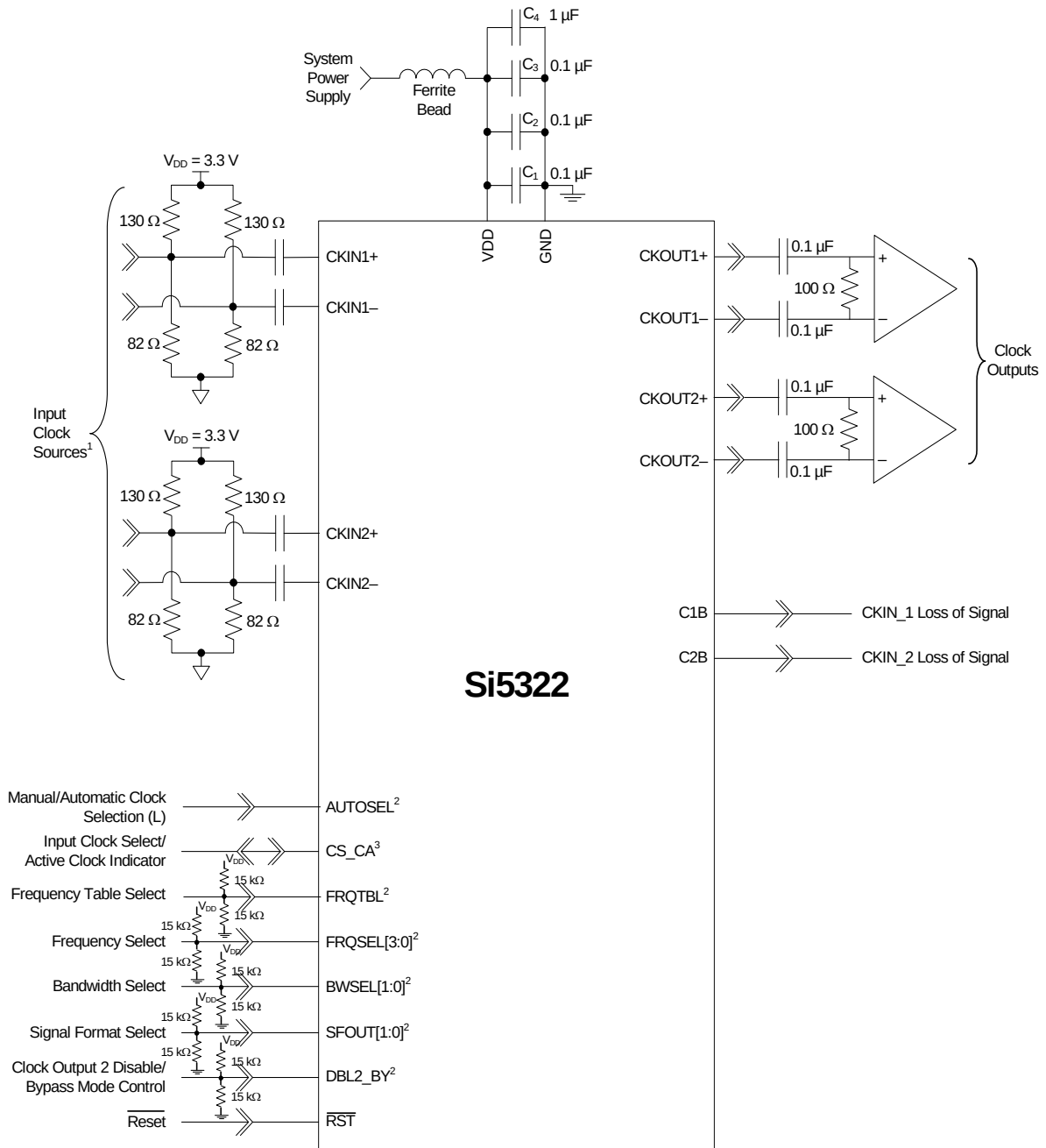


Figure 5. Typical Phase Noise Plot

Table 8. Typical Jitter Data

Jitter Bandwidth	RMS Jitter (fs)
OC-48, 12 kHz to 20 MHz	374
OC-192, 20 kHz to 80 MHz	388
OC-192, 4 MHz to 80 MHz	181
OC-192, 50 kHz to 80 MHz	377
Broadband, 800 Hz to 80 MHz	420



Notes: 1. Assumes differential LVEPECL termination (3.3 V) on clock inputs.
 2. Denotes tri-level input pins with states designated as L (ground), M ($V_{DD}/2$), and H (V_{DD}).
 3. Assumes manual input clock selection.

Figure 6. Si5322 Typical Application Circuit

2. Functional Description

The Si5322 is a low jitter, precision clock multiplier for high-speed communication systems, including SONET OC-48/OC-192, SDH STM-16/64 Ethernet, and Fibre Channel. The Si5322 accepts dual clock inputs ranging from 19.44 to 707 MHz and generates two frequency-multiplied clock outputs ranging from 19.44 to 1050 MHz. The two input clocks are at the same frequency and the two output clocks are at the same frequency. The input clock frequency and clock multiplication ratio are selectable from a table of popular SONET, Ethernet, and Fibre Channel rates. In addition to providing clock multiplication in SONET and datacom applications, the Si5322 supports SONET-to-datacom frequency translations. Silicon Laboratories offers a PC-based software utility, *DSPLLsim*, that can be used to look up valid Si5322 frequency translations. This utility can be downloaded from <http://www.silabs.com/timing> (click on Documentation).

The Si5322 is recommended for applications in which the input clock is relatively low jitter and only clock multiplication is required. The Si5322 is based on Silicon Laboratories' 3rd-generation DSPLL[®] technology, which provides any-frequency synthesis in a highly integrated PLL solution that eliminates the need for external VCXO and loop filter components. The Si5322 PLL loop bandwidth is selectable via the BWSEL[1:0] pins and supports a range from 150 kHz to 1.5 MHz. The *DSPLLsim* software utility can be used to calculate valid loop bandwidth settings for a given input clock frequency/clock multiplication ratio. The Si5322 monitors all input clocks for loss of signal and provides a LOS alarm when it detects a missing clock.

In the case when the input clocks enter alarm conditions, the PLL will freeze the DCO output frequency near its last value to maintain operation with an internal state close to the last valid operating state.

The Si5322 has two differential clock outputs. The electrical format of the clock outputs is programmable to support LVPECL, LVDS, CML, or CMOS loads. If not required, the second clock output can be powered down to minimize power consumption. For system-level debugging, a bypass mode is available which drives the output clock directly from the input clock, bypassing the internal DSPLL. The device is powered by a single 1.8, 2.5, or 3.3 V supply.

2.1. Further Documentation

Consult the Silicon Laboratories Any-Frequency Precision Clock Family Reference Manual (FRM) for detailed information about the Si5322. Additional design support is available from Silicon Laboratories through your distributor.

Silicon Laboratories has developed a PC-based software utility called *DSPLLsim* to simplify device configuration, including frequency planning and loop bandwidth selection. The FRM and this utility can be downloaded from <http://www.silabs.com/timing>; click on Documentation.

3. Pin Descriptions: Si5322

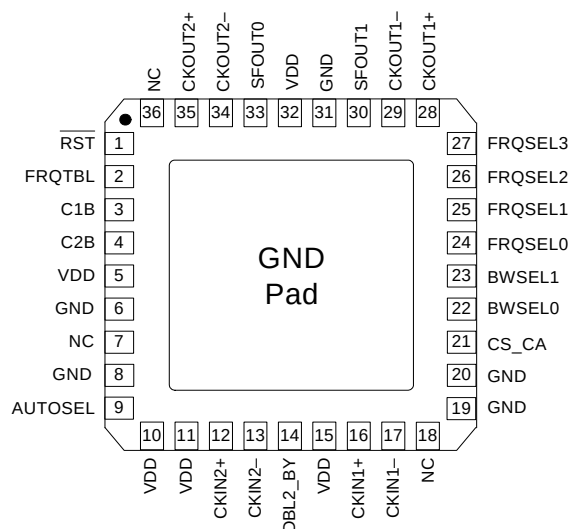


Table 9. Si5322 Pin Descriptions

Pin #	Pin Name	I/O	Signal Level	Description
1	$\overline{\text{RST}}$	I	LVC MOS	External Reset. Active low input that performs external hardware reset of device. Resets all internal logic to a known state. Clock outputs are tristated during reset. After rising edge of RST signal, the Si5322 will perform an internal self-calibration. This pin has a weak pull-up.
2	FRQTBL	I	3-Level	Frequency Table Select. Selects SONET/SDH, datacom, or SONET/SDH to datacom frequency table. L = SONET/SDH. M = Datacom. H = SONET/SDH to Datacom. The pin has a weak pull-up and weak pull-down and defaults to M. Some designs may require an external resistor voltage divider when driven by an active device that will tri-state.
3	C1B	O	LVC MOS	CKIN1 Loss of Signal. Active high loss-of-signal indicator for CKIN1. Once triggered, the alarm will remain active until CKIN1 is validated. 0 = CKIN1 present. 1 = LOS on CKIN1.
4	C2B	O	LVC MOS	CKIN2 Loss of Signal. Active high loss-of-signal indicator for CKIN2. Once triggered, the alarm will remain active until CKIN2 is validated. 0 = CKIN2 present. 1 = LOS on CKIN2.

Table 9. Si5322 Pin Descriptions (Continued)

Pin #	Pin Name	I/O	Signal Level	Description
5, 10, 11, 15, 32	V _{DD}	V _{DD}	Supply	Supply. The device operates from a 1.8, 2.5, or 3.3 V supply. Bypass capacitors should be associated with the following V _{DD} pins: 5 0.1 µF 10 0.1 µF 32 0.1 µF A 1.0 µF should be placed as close to device as is practical.
6, 8, 19, 20, 31	GND	GND	Supply	Ground. Must be connected to system ground. Minimize the ground path impedance for optimal performance of this device.
9	AUTOSEL	I	3-Level	Manual/Automatic Clock Selection. Three level input that selects the method of input clock selection to be used. L = Manual. M = Automatic non-revertive. H = Automatic revertive. The pin has a weak pull-up and weak pull-down and defaults to M. Some designs may require an external resistor voltage divider when driven by an active device that will tri-state.
12 13	CKIN2+ CKIN2–	I	Multi	Clock Input 2. Differential input clock. This input can also be driven with a single-ended signal. Input frequency selected from a table of values. The same frequency must be applied to CKIN1 and CKIN2.
14	DBL2_BY	I	3-Level	Output 2 Disable/Bypass Mode Control. Controls enable of CKOUT2 divider/output buffer path and PLL bypass mode. L = CKOUT2 enabled. M = CKOUT2 disabled. H = Bypass mode with CKOUT2 enabled. CMOS outputs do not support Bypass Mode. The pin has a weak pull-up and weak pull-down and defaults to M. Some designs may require an external resistor voltage divider when driven by an active device that will tri-state.
16 17	CKIN1+ CKIN1–	I	Multi	Clock Input 1. Differential input clock. This input can also be driven with a single-ended signal. Input frequency selected from a table of values. The same frequency must be applied to CKIN1 and CKIN2.

Table 9. Si5322 Pin Descriptions (Continued)

Pin #	Pin Name	I/O	Signal Level	Description
21	CS_CA	I/O	LVC MOS	Input Clock Select/Active Clock Indicator. Input: If manual clock selection mode is chosen (AUTOSEL = L), this pin functions as the manual input clock selector. This input is internally deglitched to prevent inadvertent clock switching during changes in the CS input state. 0 = Select CKIN1. 1 = Select CKIN2. If configured as input, must be set high or low. Output: If automatic clock selection mode is chosen (AUTOSEL = M or H), this pin indicates which of the two input clocks is currently the active clock. If alarms exist on both CKIN1 and CKIN2, indicating that the digital hold state has been entered, CA will indicate the last active clock that was used before entering the hold state. 0 = CKIN1 active input clock. 1 = CKIN2 active input clock.
23 22	BWSEL1 BWSEL0	I	3-Level	Bandwidth Select. Three level inputs that select the DSPLL closed loop bandwidth. Detailed operations and timing characteristics for these pins may be found in the Any-Frequency Precision Clock Family Reference Manual. These pins have both weak pull-ups and weak pull-downs and default to M. Some designs may require an external resistor voltage divider when driven by an active device that will tri-state.
27 26 25 24	FRQSEL3 FRQSEL2 FRQSEL1 FRQSEL0	I	3-Level	Multiplier Select. Three level inputs that select the input clock and clock multiplication ratio, depending on the FRQTBL setting. Consult the Any-Frequency Precision Clock Family Reference Manual or DSPLLsim configuration software for settings, both available for download at www.silabs.com/timing (click on Documentation). These pins have both weak pull-ups and weak pull-downs and default to M. Some designs may require an external resistor voltage divider when driven by an active device that will tri-state.

Table 9. Si5322 Pin Descriptions (Continued)

Pin #	Pin Name	I/O	Signal Level	Description																				
33 30	SFOUT0 SFOUT1	I	3-Level	Signal Format Select. Three level inputs that select the output signal format (common mode voltage and differential swing) for both CKOUT1 and CKOUT2. Valid settings include LVPECL, LVDS, and CML. Also includes selections for CMOS mode, tristate mode, and tristate/sleep mode. <table><tr><th>SFOUT[1:0]</th><th>Signal Format</th></tr><tr><td>HH</td><td>Reserved</td></tr><tr><td>HM</td><td>LVDS</td></tr><tr><td>HL</td><td>CML</td></tr><tr><td>MH</td><td>LVPECL</td></tr><tr><td>MM</td><td>Reserved</td></tr><tr><td>ML</td><td>LVDS—Low Swing</td></tr><tr><td>LH</td><td>CMOS</td></tr><tr><td>LM</td><td>Disabled</td></tr><tr><td>LL</td><td>Reserved</td></tr></table> CMOS outputs do not support Bypass Mode. These pins have both weak pull-ups and weak pull-downs and default to M. Some designs may require an external resistor voltage divider when driven by an active device that will tri-state.	SFOUT[1:0]	Signal Format	HH	Reserved	HM	LVDS	HL	CML	MH	LVPECL	MM	Reserved	ML	LVDS—Low Swing	LH	CMOS	LM	Disabled	LL	Reserved
SFOUT[1:0]	Signal Format																							
HH	Reserved																							
HM	LVDS																							
HL	CML																							
MH	LVPECL																							
MM	Reserved																							
ML	LVDS—Low Swing																							
LH	CMOS																							
LM	Disabled																							
LL	Reserved																							
34 35	CKOUT2– CKOUT2+	O	Multi	Clock Output 2. Differential output clock with a frequency selected from a table of values. Output signal format is selected by SFOUT pins. Output is differential for LVPECL, LVDS, and CML compatible modes. For CMOS format, both output pins drive identical single-ended clock outputs.																				
29 28	CKOUT1– CKOUT1+	O	Multi	Clock Output 1. Differential output clock with a frequency selected from a table of values. Output signal format is selected by SFOUT pins. Output is differential for LVPECL, LVDS, and CML compatible modes. For CMOS format, both output pins drive identical single-ended clock outputs.																				
7, 18, 36	NC	—	—	No Connect. These pins must be left unconnected for normal operation.																				
GND PAD	GND	GND	Supply	Ground Pad. The ground pad must provide a low thermal and electrical impedance to a ground plane.																				

4. Ordering Guide

Ordering Part Number	Package	ROHS6, Pb-Free	Temperature Range
Si5322-C-GM*	36-Lead 6 x 6 mm QFN	Yes	–40 to 85 °C
*Note: Not recommended for new designs. For alternatives, see the Si533x family.			

5. Package Outline: 36-Pin QFN

Figure 7 illustrates the package details for the Si5322. Table 10 lists the values for the dimensions shown in the illustration.

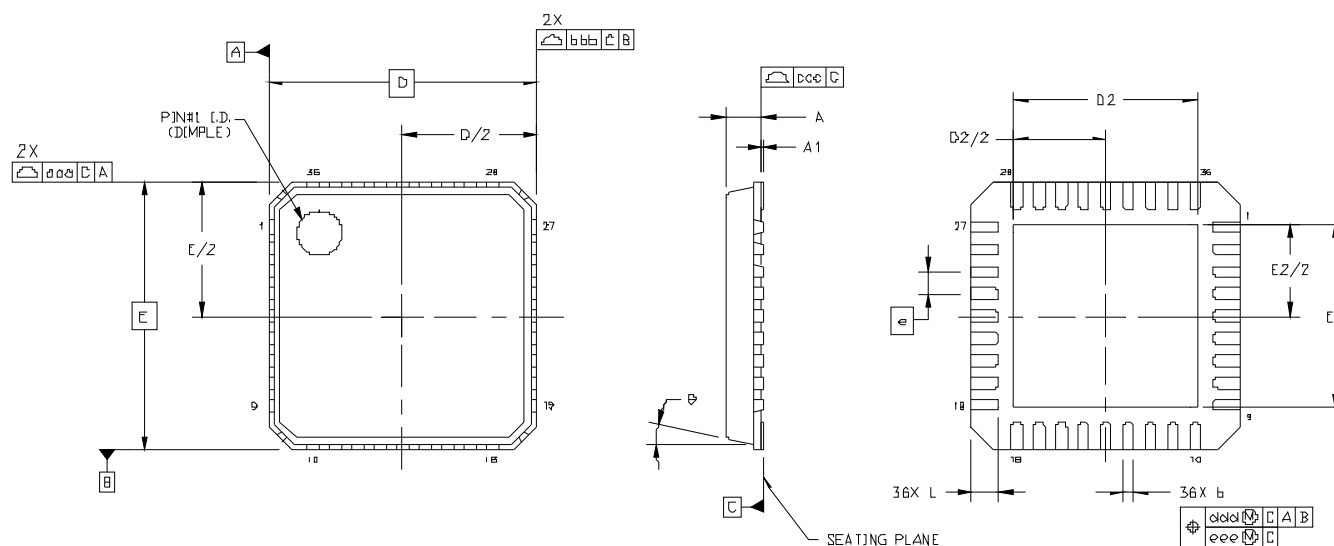


Figure 7. 36-Pin Quad Flat No-lead (QFN)

Table 10. Package Dimensions

Symbol	Millimeters		
	Min	Nom	Max
A	0.80	0.85	0.90
A1	0.00	0.02	0.05
b	0.18	0.25	0.30
D	6.00 BSC		
D2	3.95	4.10	4.25
e	0.50 BSC		
E	6.00 BSC		
E2	3.95	4.10	4.25

Symbol	Millimeters		
	Min	Nom	Max
L	0.50	0.60	0.70
θ	—	—	12°
aaa	—	—	0.10
bbb	—	—	0.10
ccc	—	—	0.08
ddd	—	—	0.10
eee	—	—	0.05

Notes:

1. All dimensions shown are in millimeters (mm) unless otherwise noted.
2. Dimensioning and Tolerancing per ANSI Y14.5M-1994.
3. This drawing conforms to JEDEC outline MO-220, variation VJJD.
4. Recommended card reflow profile is per the JEDEC/IPC J-STD-020C specification for Small Body Components.

6. Land Pattern: 36-Pin QFN

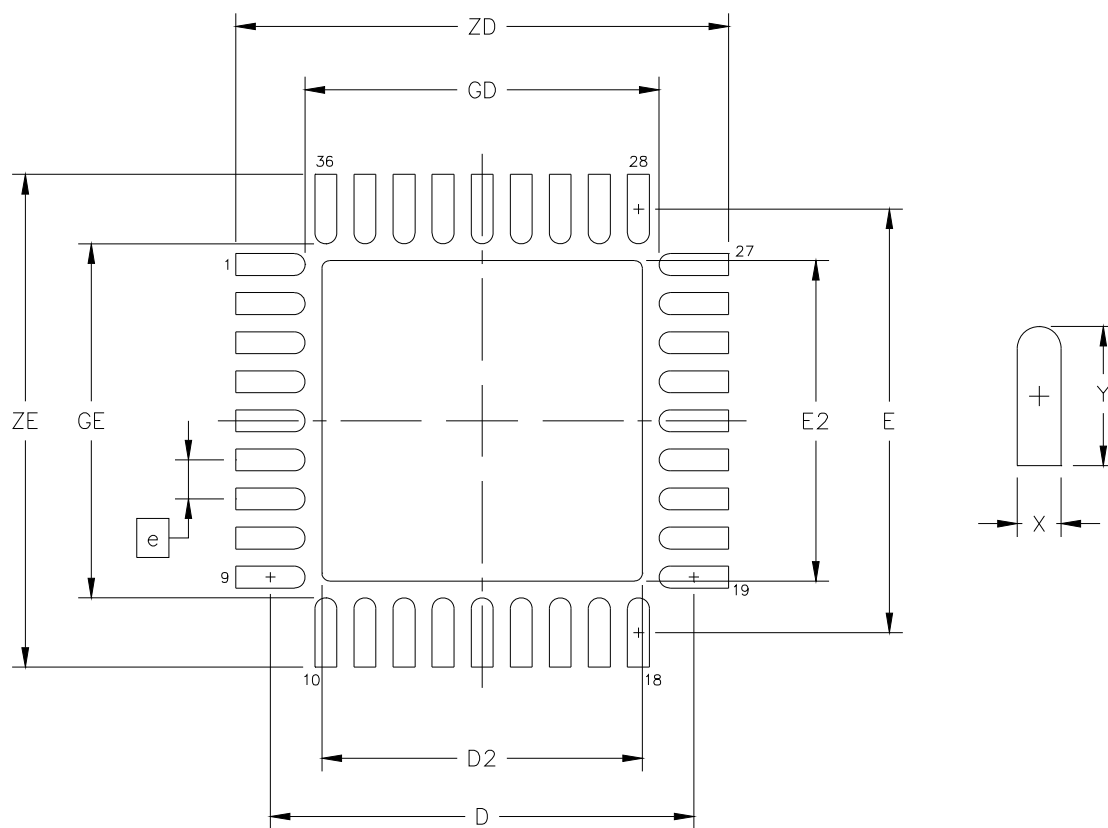


Figure 8. 36-Pin QFN Land Pattern

Table 11. PCB Land Pattern Dimensions

Dimension	MIN	MAX
e	0.50 BSC.	
E	5.42 REF.	
D	5.42 REF.	
E2	4.00	4.20
D2	4.00	4.20
GE	4.53	—
GD	4.53	—
X	—	0.28
Y	0.89 REF.	
ZE	—	6.31
ZD	—	6.31

Notes:**General**

1. All dimensions shown are in millimeters (mm) unless otherwise noted.
2. Dimensioning and Tolerancing is per the ANSI Y14.5M-1994 specification.
3. This Land Pattern Design is based on IPC-SM-782 guidelines.
4. All dimensions shown are at Maximum Material Condition (MMC). Least Material Condition (LMC) is calculated based on a Fabrication Allowance of 0.05 mm.

Solder Mask Design

5. All metal pads are to be non-solder mask defined (NSMD). Clearance between the solder mask and the metal pad is to be 60 μ m minimum, all the way around the pad.

Stencil Design

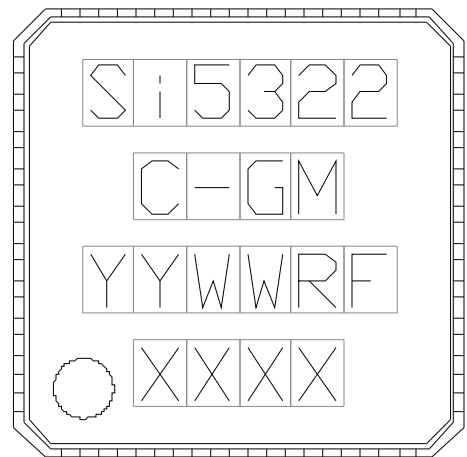
6. A stainless steel, laser-cut and electro-polished stencil with trapezoidal walls should be used to assure good solder paste release.
7. The stencil thickness should be 0.125 mm (5 mils).
8. The ratio of stencil aperture to land pad size should be 1:1 for the perimeter pads.
9. A 4 x 4 array of 0.80 mm square openings on 1.05 mm pitch should be used for the center ground pad.

Card Assembly

10. A No-Clean, Type-3 solder paste is recommended.
11. The recommended card reflow profile is per the JEDEC/IPC J-STD-020C specification for Small Body Components.

7. Top Marking

7.1. Si5322 Top Marking (QFN)



7.2. Top Marking Explanation

Mark Method:	Laser	
Font Size:	0.80 mm Right-Justified	
Line 1 Marking:	Si5322	Customer Part Number See Ordering Guide for options
Line 2 Marking:	C-GM	C = Product Revision G = Temperature Range –40 to 85 °C (RoHS6) M = QFN Package
Line 3 Marking:	YYWWRF	YY = Year WW = Work Week R = Die Revision F = Internal code Assigned by the Assembly House. Corresponds to the year and work week of the mold date.
Line 4 Marking:	Pin 1 Identifier	Circle = 0.75 mm Diameter Lower-Left Justified
	XXXX	Internal Code

DOCUMENT CHANGE LIST

Revision 0.44 to Revision 0.45

- Condensed format.

Revision 0.45 to Revision 0.46

- Removed references to latency control, INC, and DEC in figures and text.
- Changed LVTTTL to LVCMOS in Table 2, "Absolute Maximum Ratings," on page 5.
- Added Figure 1, "Typical Phase Noise Plot," on page 4.
- Updated "3. Pin Descriptions: Si5322".
- Added "6. Land Pattern: 36-Pin QFN".

Revision 0.46 to Revision 0.47

- Removed Figure 1. "Typical Phase Noise Plot."
- Changed pins 11 and 15 from NC to VDD in "3. Pin Descriptions: Si5322".

Revision 0.47 to Revision 0.5

- Changed 1.8 V operating range to $\pm 5\%$.
- Updated Table 1 on page 4.
- Updated Table 2 on page 5.
- Updated Figure 6 on page 12 to add pull-up/pull-down resistors for 3-level inputs.
- Added figure and table on page 11.
- Updated "2. Functional Description" on page 13.
- Clarified "3. Pin Descriptions: Si5322" on page 14.
- Updated SFOUT values.

Revision 0.5 to Revision 0.51

- Changed "any-rate" to "any-frequency" throughout.
- Expanded spec tables 1 through 7.
- Updated Table 5 on page 10.
- Added "7. Top Marking" on page 22.
- Added clarification that CMOS output format is not available in PLL bypass mode.
- Updated "4. Ordering Guide" on page 18.
- Removed note from "3. Pin Descriptions: Si5322" on page 14.



ClockBuilder Pro

One-click access to Timing tools, documentation, software, source code libraries & more. Available for Windows and iOS (CBGo only).

www.silabs.com/CBPro



Timing Portfolio
www.silabs.com/timing



SW/HW
www.silabs.com/CBPro



Quality
www.silabs.com/quality



Support and Community
community.silabs.com

Disclaimer

Silicon Laboratories intends to provide customers with the latest, accurate, and in-depth documentation of all peripherals and modules available for system and software implementers using or intending to use the Silicon Laboratories products. Characterization data, available modules and peripherals, memory sizes and memory addresses refer to each specific device, and "Typical" parameters provided can and do vary in different applications. Application examples described herein are for illustrative purposes only. Silicon Laboratories reserves the right to make changes without further notice and limitation to product information, specifications, and descriptions herein, and does not give warranties as to the accuracy or completeness of the included information. Silicon Laboratories shall have no liability for the consequences of use of the information supplied herein. This document does not imply or express copyright licenses granted hereunder to design or fabricate any integrated circuits. The products must not be used within any Life Support System without the specific written consent of Silicon Laboratories. A "Life Support System" is any product or system intended to support or sustain life and/or health, which, if it fails, can be reasonably expected to result in significant personal injury or death. Silicon Laboratories products are generally not intended for military applications. Silicon Laboratories products shall under no circumstances be used in weapons of mass destruction including (but not limited to) nuclear, biological or chemical weapons, or missiles capable of delivering such weapons.

Trademark Information

Silicon Laboratories Inc., Silicon Laboratories, Silicon Labs, SiLabs and the Silicon Labs logo, CMEMS®, EFM, EFM32, EFR, Energy Micro, Energy Micro logo and combinations thereof, "the world's most energy friendly microcontrollers", Ember®, EZLink®, EZMac®, EZRadio®, EZRadioPRO®, DSPLL®, ISOModem®, Precision32®, ProSLIC®, SiPHY®, USBXpress® and others are trademarks or registered trademarks of Silicon Laboratories Inc. ARM, CORTEX, Cortex-M3 and THUMB are trademarks or registered trademarks of ARM Holdings. Keil is a registered trademark of ARM Limited. All other products or brand names mentioned herein are trademarks of their respective holders.



Silicon Laboratories Inc.
400 West Cesar Chavez
Austin, TX 78701
USA

<http://www.silabs.com>